## Gas Sensing with Nanocrystalline Tetragonal WO<sub>3</sub> Films

L. F. Reyes<sup>1,2</sup>, S. Saukko<sup>1</sup>, A. Hoel<sup>2</sup>, P. Heszler<sup>2</sup>, V. Lantto<sup>1</sup>, C. G. Granqvist<sup>2</sup> and J. Lappalainen<sup>1</sup>

<sup>1</sup>Microelectronics and Materials Physics Laboratories, University of Oulu, P.O. Box 4500, FIN-90014 University of Oulu, Finland

<sup>2</sup>Department of Engineering Sciences, The Ångström Laboratory, Uppsala University, P.O. Box 534, SE-75121 Uppsala, Sweden

## Abstract

A high-temperature route employing advanced reactive gas deposition was used to produce WO<sub>3</sub> nanoparticles with the metastable tetragonal crystal structure for gassensing applications. WO<sub>3</sub> thick films of the produced nanoparticles were deposited on alumina substrates with pre-printed gold electrodes, being 200 µm apart, and a Pt heating resistor printed on the reverse side. WO<sub>3</sub> is an extrinsic n-type semiconductor and its crystal structure is lowered from the ideal cubic symmetry of the metallic ReO<sub>3</sub> and isoelectronic NaWO<sub>3</sub> bronze. The oxygen octahedra in WO<sub>3</sub> are deformed and tilted and the metal cation lies off-center. Because of this great flexibility inherent in the structure, there are many different types of distortions (phases) at different temperatures and the physical properties of the structures depend crucially on the details of these distortions. The high-temperature tetragonal phase of WO<sub>3</sub> has a layered structure perpendicular to the tetragonal c axis, which implies a stable (001) surface for tetragonal crystallites. This layered crystal structure is interesting from the point of gas sensing, since it contains terminal-like W = 0 bonds on both sides of each layer through the structure, in addition to surfaces, and also large 12-fold coordinated cages for ion insertion into the structure.

The WO<sub>3</sub> films were very sensitive, e.g., to  $H_2S$  already at room temperature and to NO<sub>2</sub> at low temperatures above about 450 K. Maximum sensitivity in synthetic air to  $H_2S$  was found at about 400 K and to NO<sub>2</sub> at about 525 K. Gas sensitivity was studied also in atmospheres having different oxygen concentrations. E.g., the temperature corresponding to the maximum sensitivity to  $H_2S$  was found to increase with decreasing oxygen concentration in the atmosphere.